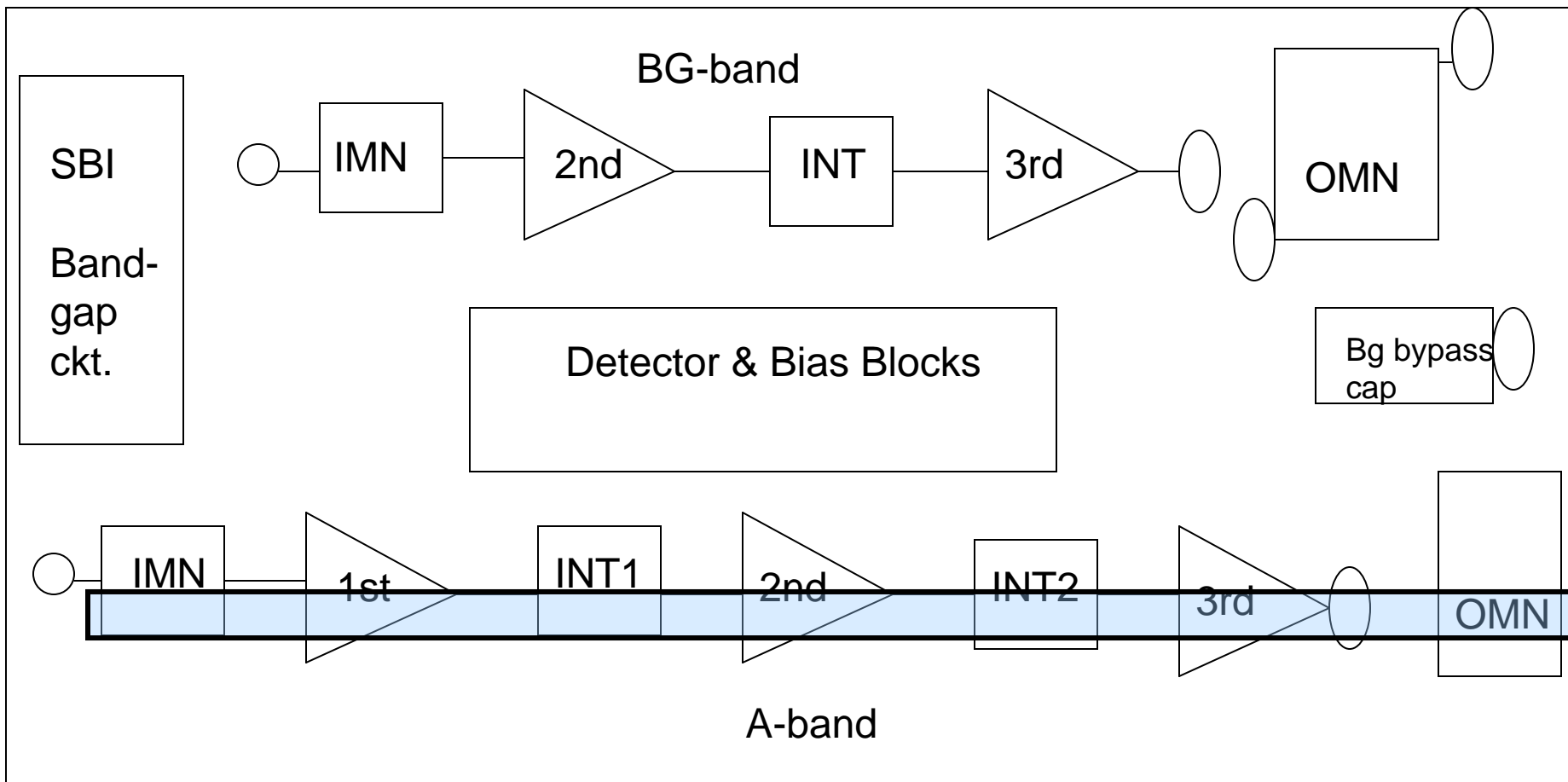




*A Fully Integrated Dual  
Band SiGe BiCMOS  
Power Amplifier for  
802.11 abg-n  
Applications*

## Dual Band Configuration.



# Conceptual Schematic for a-band PA

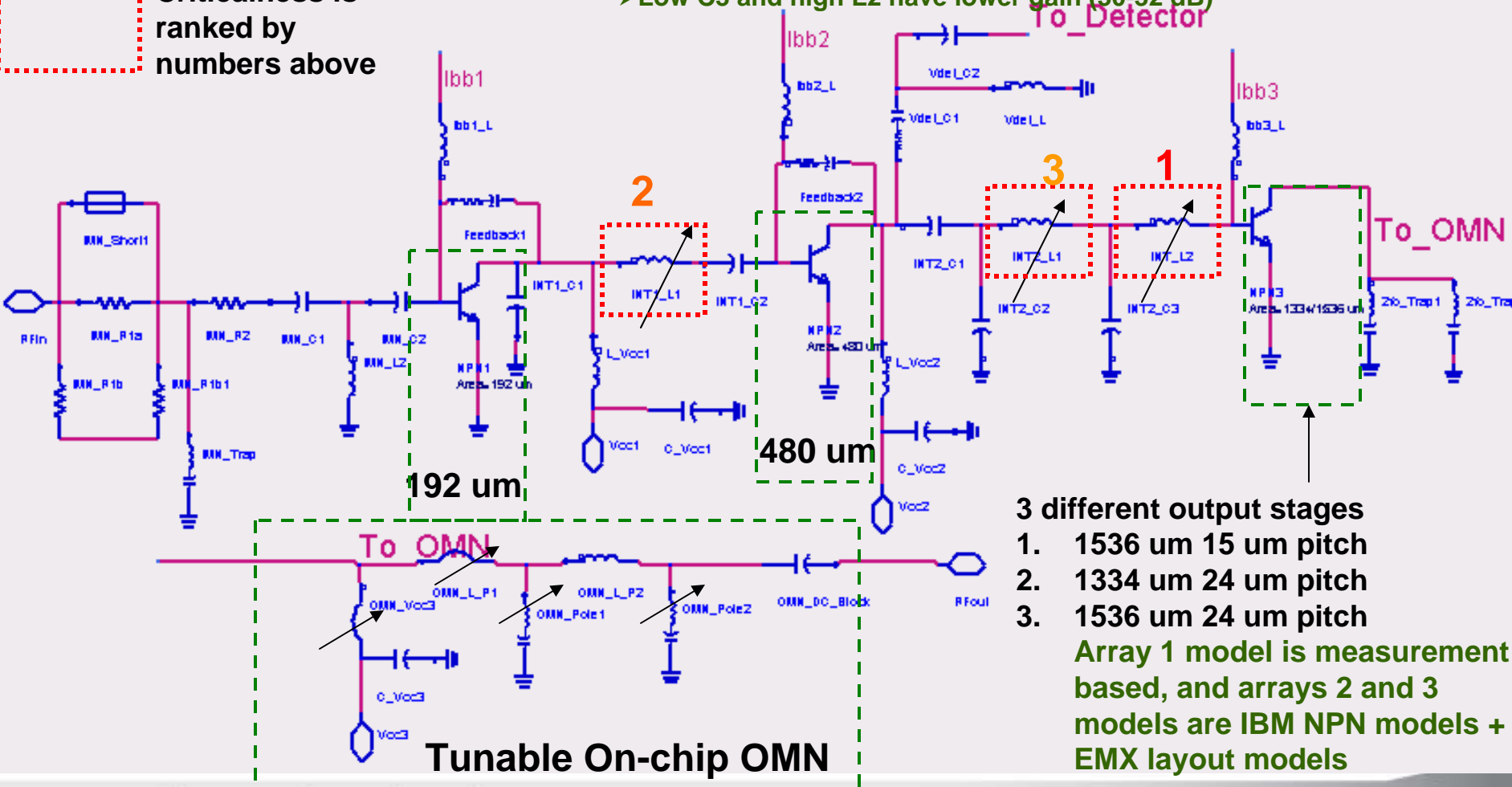
Critical Tuning  
Criticalness is ranked by numbers above

Note:

L2 and C3 play against each other.

➤ High C3 and Low L2 will have high gain (34-38 dB).

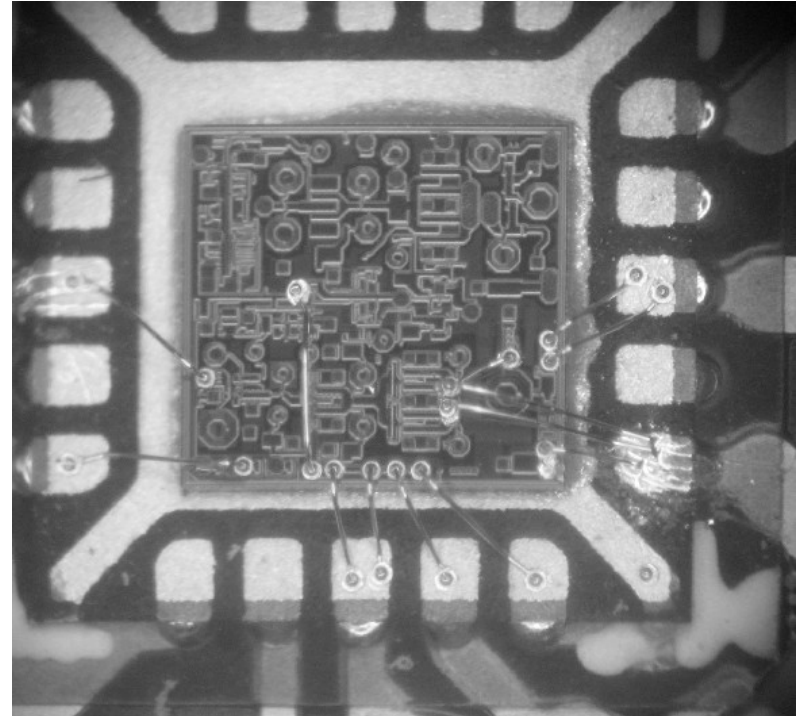
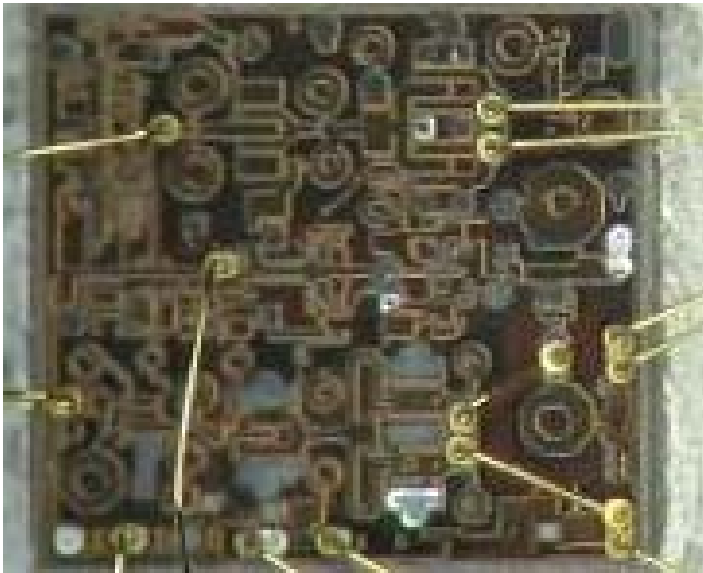
➤ Low C3 and high L2 have lower gain (30-32 dB)

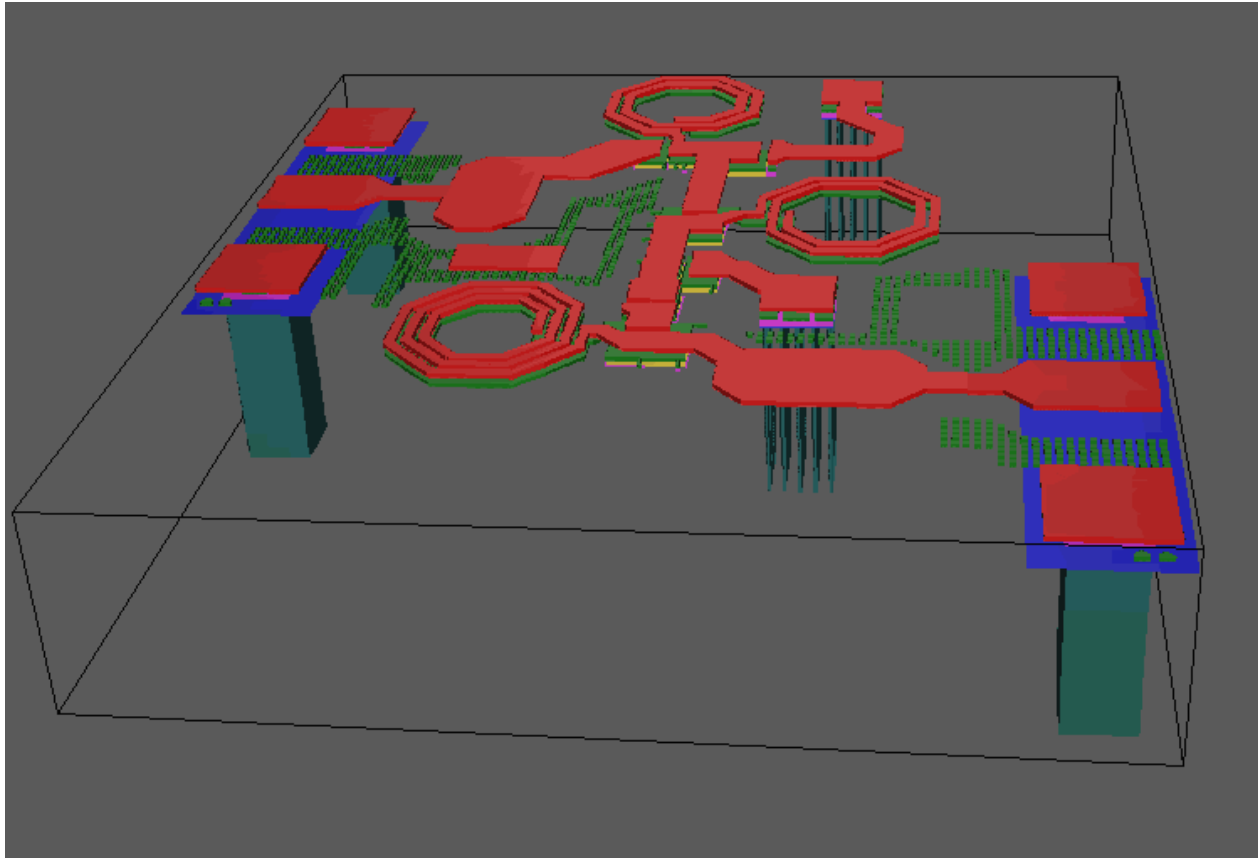


3 different output stages

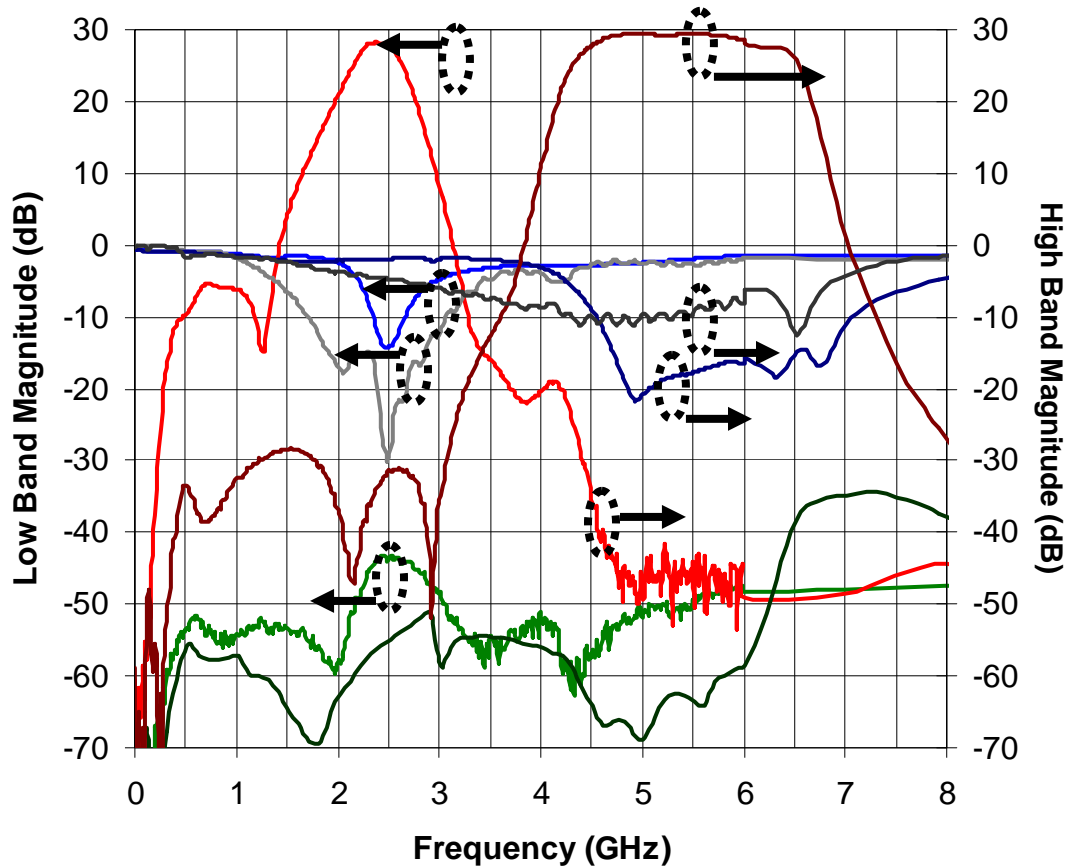
1. 1536 um 15 um pitch
2. 1334 um 24 um pitch
3. 1536 um 24 um pitch

Array 1 model is measurement based, and arrays 2 and 3 models are IBM NPN models + EMX layout models



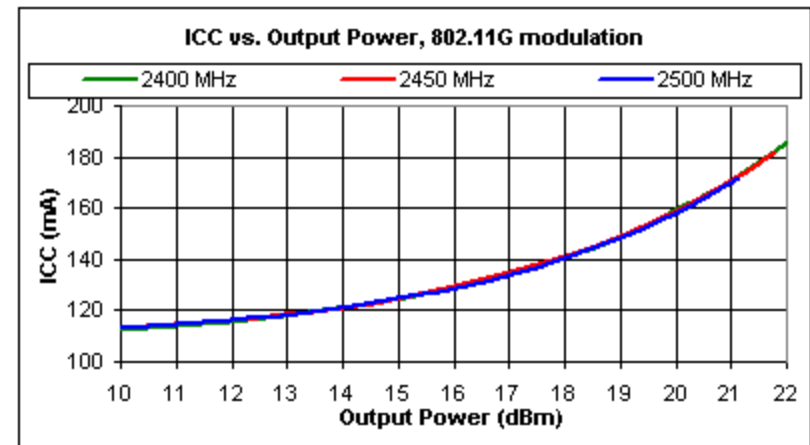
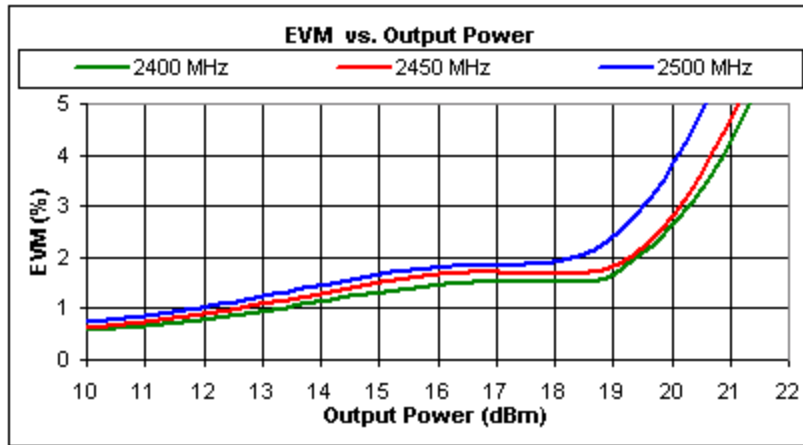


# Dual band gain response overlay

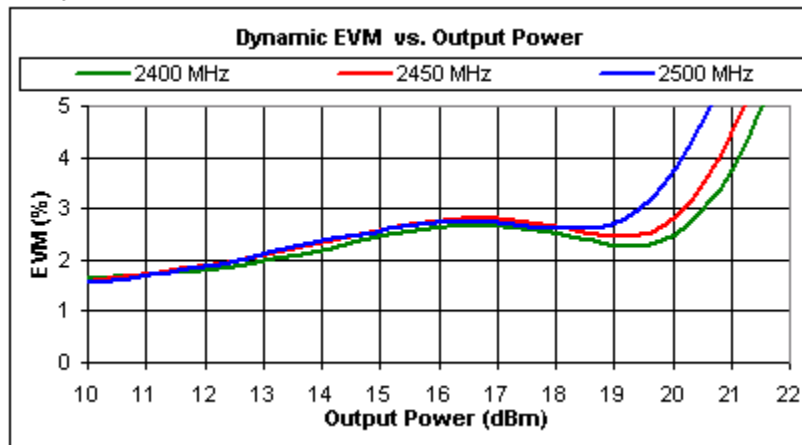


Peter: Taken from SE2580, external match

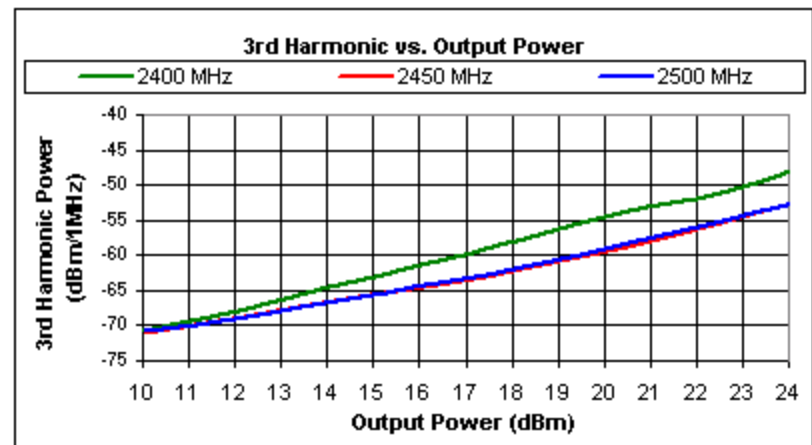
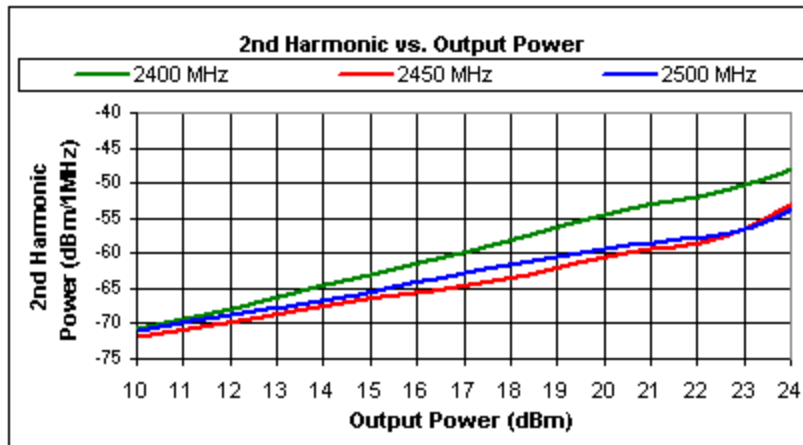
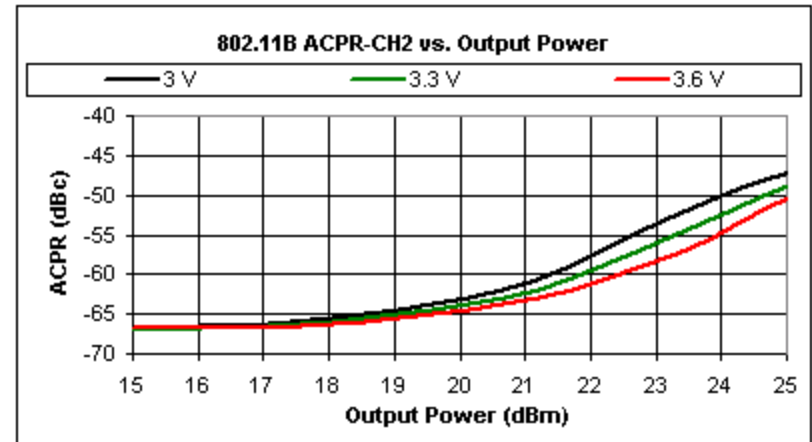
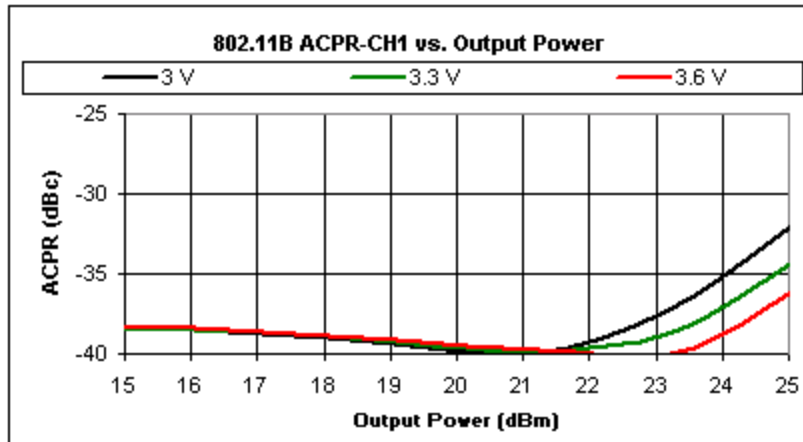
static



dynamic

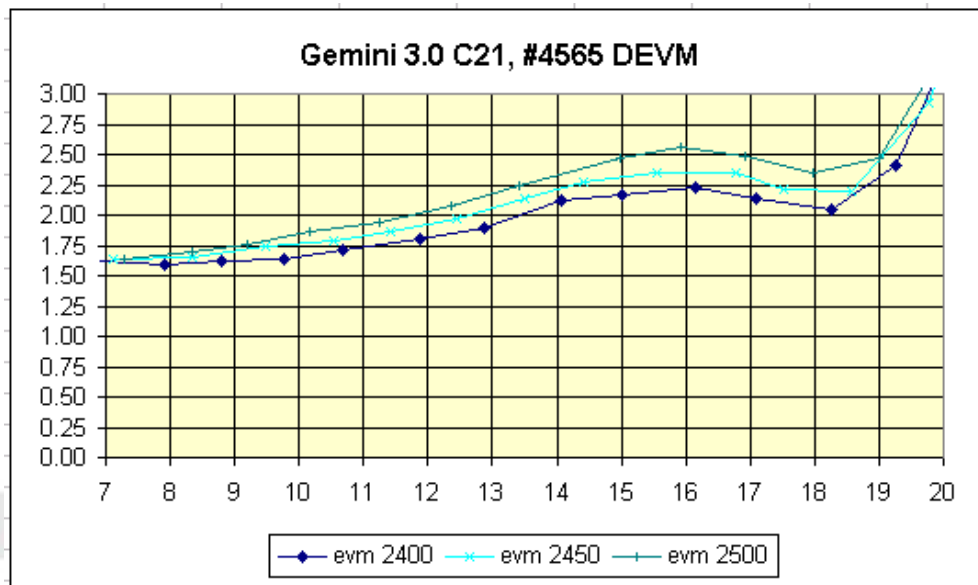
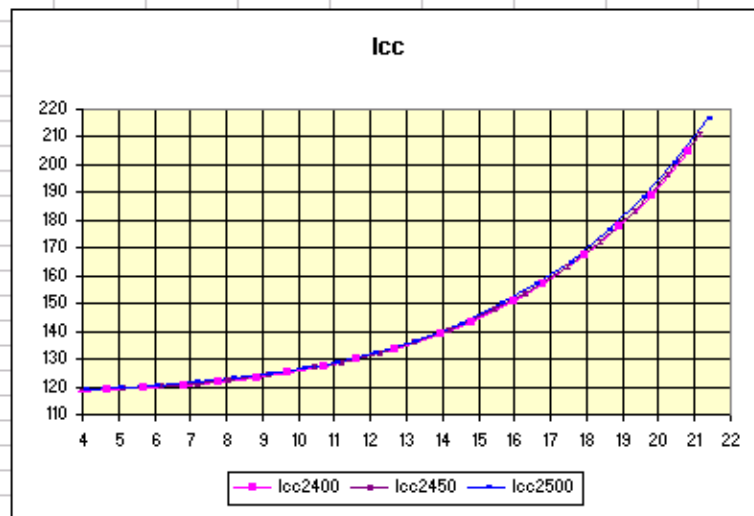
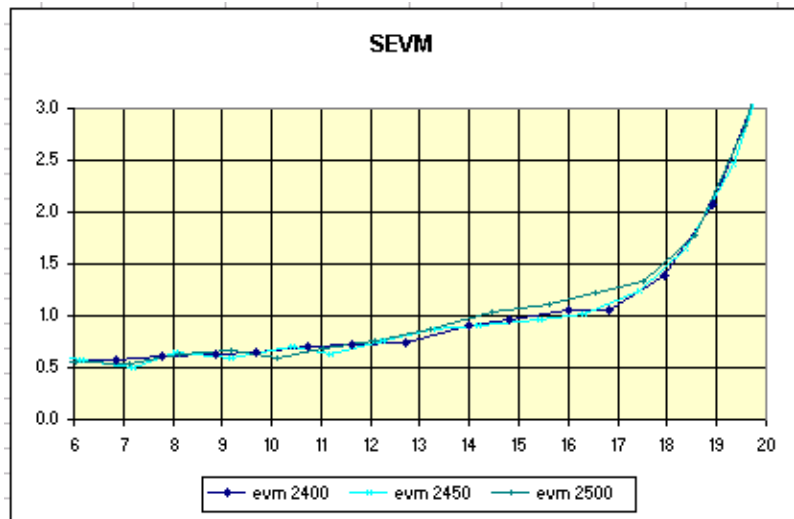


Peter: Taken from SE2580, external match

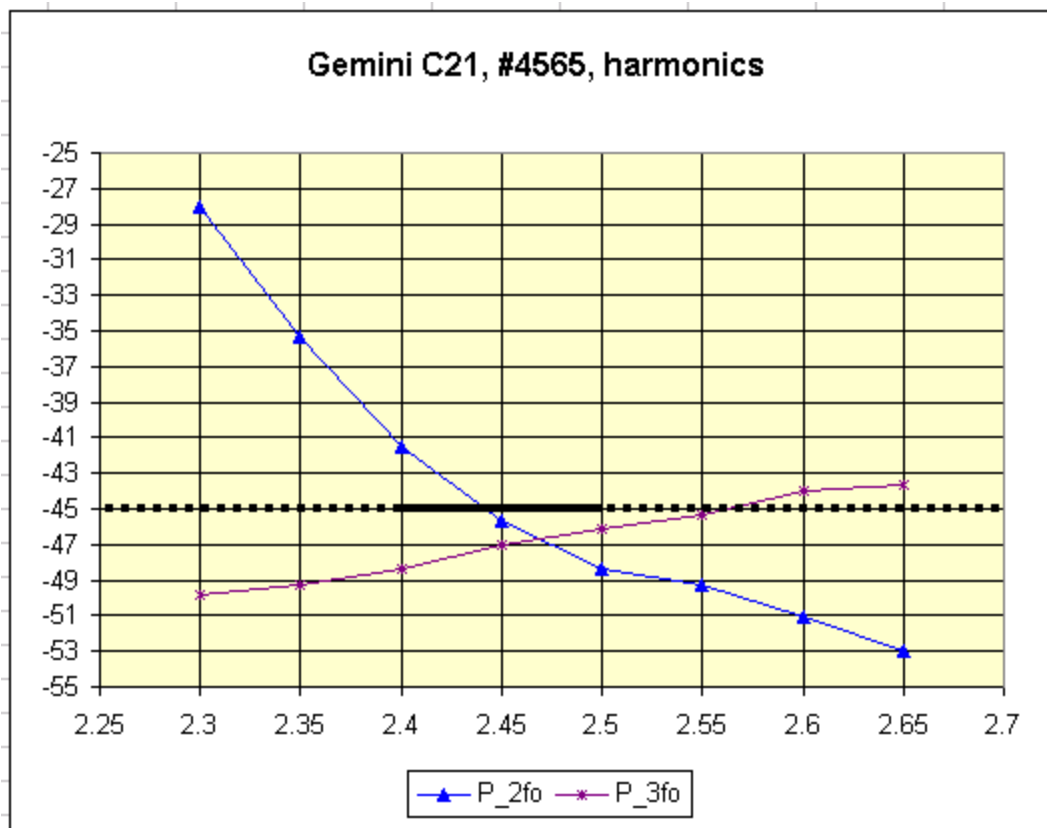




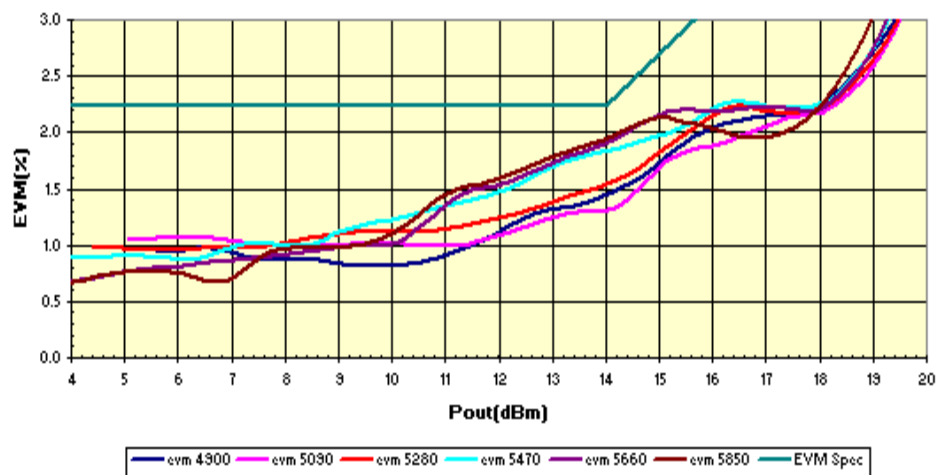
Peter: Taken from Gemini C21, internal match



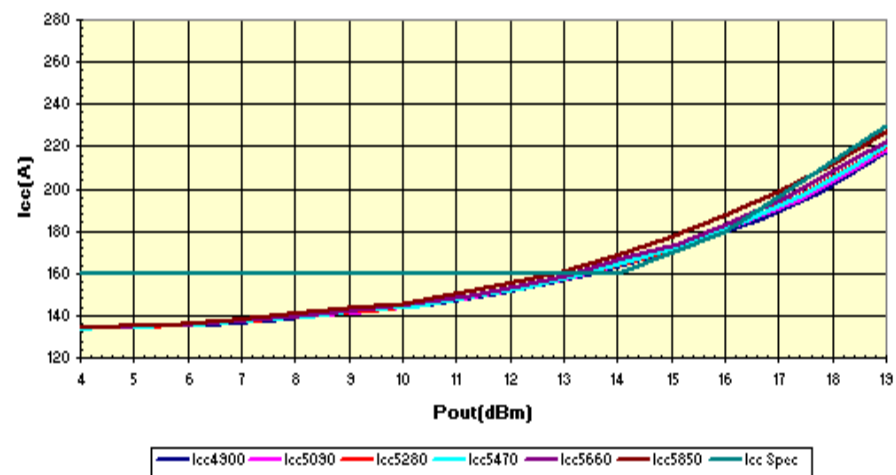
Peter: Taken from Gemini C21, internal match

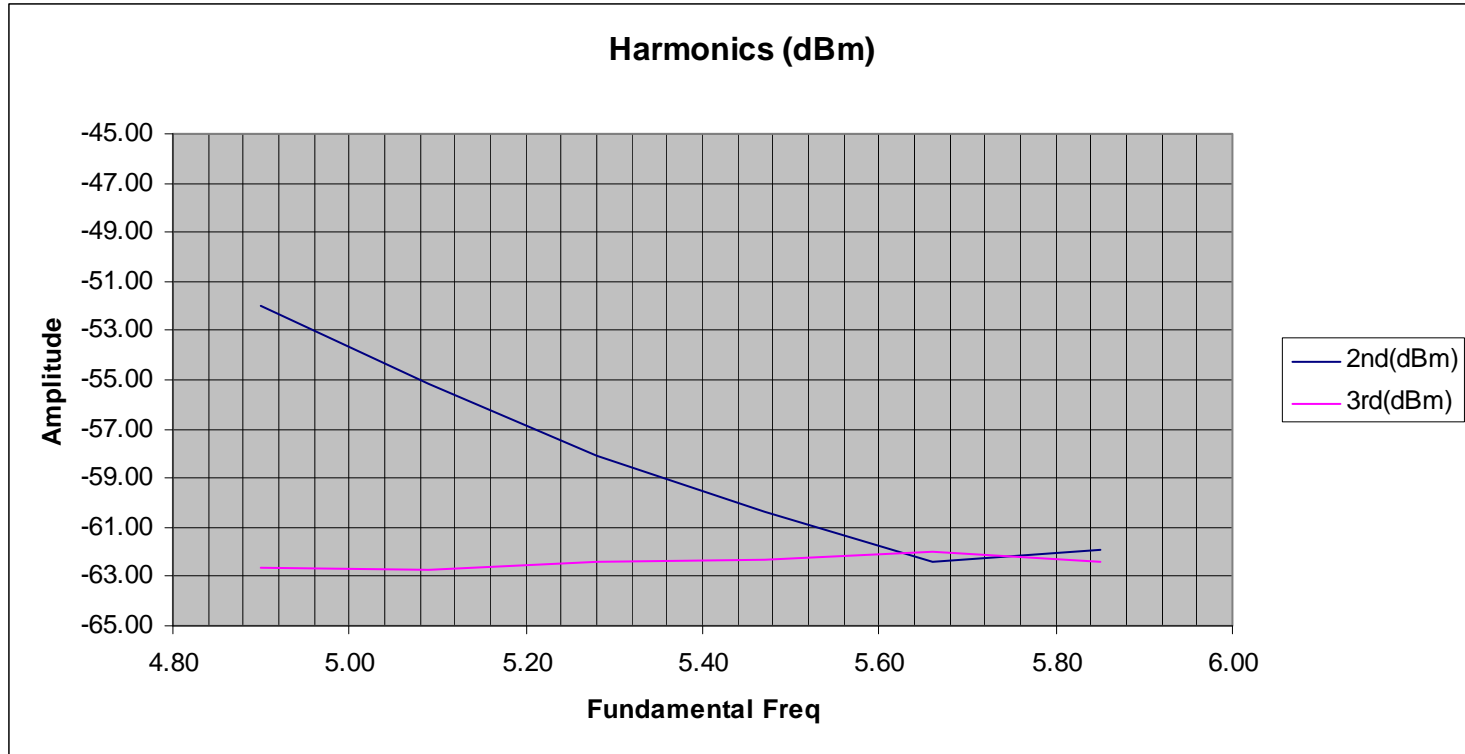


Hi LIN DEVM Int2 cut cuts (10, 55, 75 A1T6)



Icc





# Example of Programmable Dynamic Evm Reduction Circuits

Conditions: 3.3V, 5.85Ghz

